

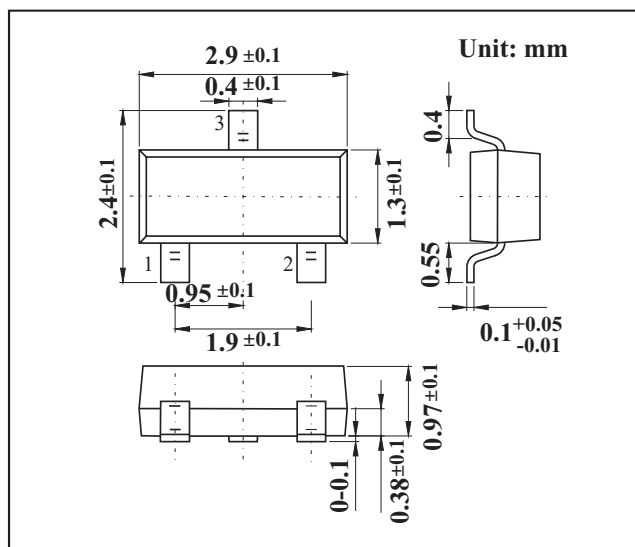
SOT-23 Small Signal Switching Diodes

FEATURES

- The plastic package carries Underwrites Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- High reliability
- High temperature soldering guaranteed: 260 °C/10 seconds at terminals
- Component in accordance to RoHs 2015/863 and WEEE 2012/19/EU

MECHANICAL DATA

- Case style: SOT-23 molded plastic
- Mounting position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

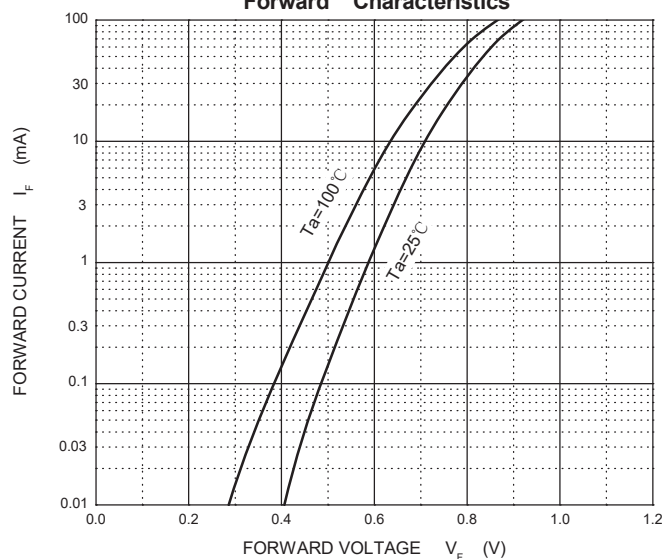
@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	85	V
DC Blocking Voltage	V_R	80	V
Forward Continuous Current	I_{FM}	300	mA
Average Rectified Output Current	I_O	100	mA
Non-Repetitive Peak Forward Surge Current @ $t=8.3ms$	I_{FSM}	2.0	A
Power Dissipation	P_D	150	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	833	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-55~+150	°C

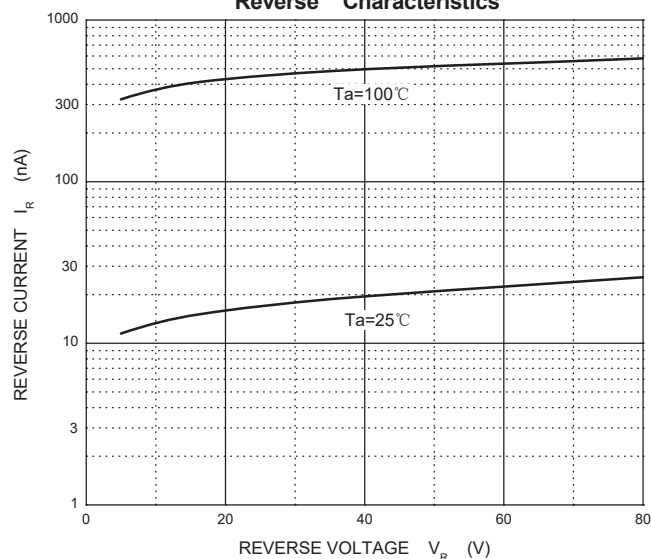
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Reverse breakdown voltage	$V_{(BR)}$	80			V	$I_R=100\mu A$
Forward voltage	V_{F1}		0.61		V	$I_F=1mA$
	V_{F2}		0.74		V	$I_F=10mA$
	V_{F3}		0.92	1.2	V	$I_F=100mA$
Reverse current	I_{R1}			0.1	μA	$V_R=30V$
	I_{R2}			0.5	μA	$V_R=80V$
Capacitance between terminals	C_T		2.2	4.0	pF	$V_R=0, f=1MHz$
Reverse recovery time	t_{rr}		1.6	4.0	ns	$I_F=I_R=10mA, I_{rr}=0.1 \times I_R$

RATINGS AND CHARACTERISTIC CURVES

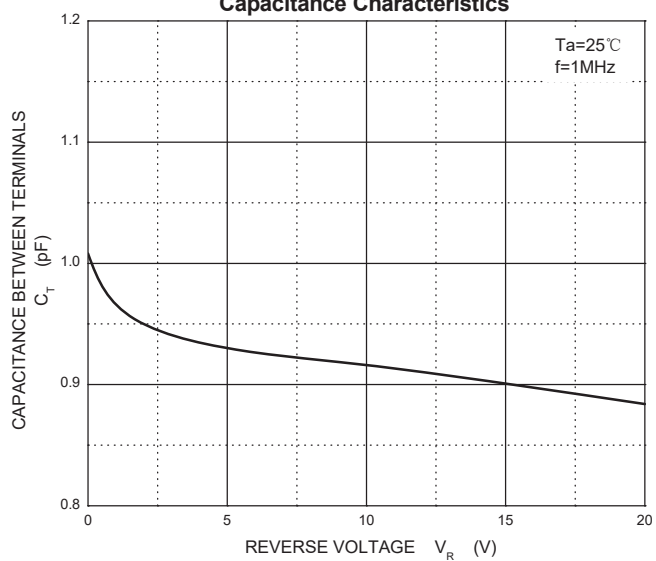
Forward Characteristics



Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

